

SMALL PACKAGE FREQUENCY UP-CONVERTER IC

DESCRIPTION

The μPC8172TK is a silicon monolithic integrated circuit designed as frequency up-converter for cellular telephone transmitter stage.

This TK suffix IC which is smaller package than conventional TB suffix IC contribute to reduce your system size.

This IC is manufactured using our 30 GHz f_{max} UHS0 (Ultra High Speed Process) silicon bipolar process.

FEATURES

- High output frequency : $f_{RFout} = 0.8$ to 2.5 GHz
- Circuit current : $I_{CC} = 9.0$ mA TYP.
- High-density surface mounting : 6-pin lead-less minimold package
- Supply voltage : $V_{CC} = 2.7$ to 3.3 V

APPLICATIONS

- PCS1900M
- 2.4 GHz band transmitter/receiver system (wireless LAN etc.)
- RF module etc.

ORDERING INFORMATION

| Part Number | Order Number | Package | Marking | Supplying Form |
|---------------|-----------------|--|---------|--|
| μ PC8172TK-E2 | μ PC8172TK-E2-A | 6-pin lead-less minimold (1511) (Pb-Free) ^{Note} | 6A | <ul style="list-style-type: none"> • Embossed tape 8 mm wide • Pin 1, 6 face the perforation side of the tape • Qty 5 kpcs/reel |

Note With regards to terminal solder (the solder contains lead) plated products (conventionally plated), contact your nearby sales office.

Remark To order evaluation samples, contact your nearby sales office.
Part number for sample order: μPC8172TK

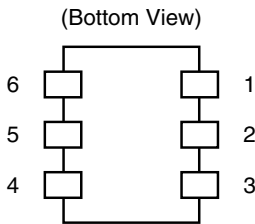
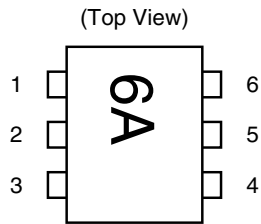
Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.
Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

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1. PIN CONNECTIONS



| Pin No. | Pin Name |
|---------|-----------------|
| 1 | IFinput |
| 2 | GND |
| 3 | LOinput |
| 4 | PS |
| 5 | V _{CC} |
| 6 | RFoutput |

Caution Pin arrangement differs from the conventional 6-pin super mini-mold type (μPC8172TB).

2. PRODUCT LINE-UP

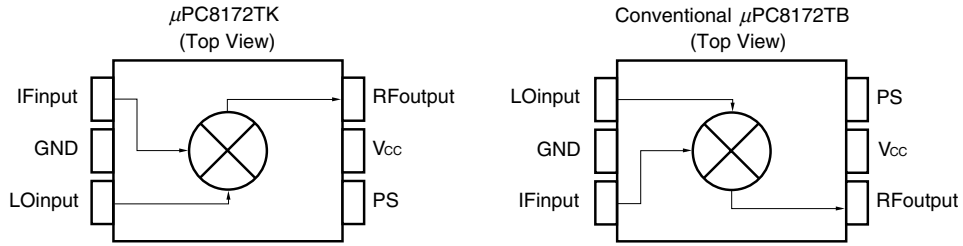
| Part No. | Package | I _{CC} (mA) | f _{RFout} (GHz) | CG (dB) | | |
|-----------|--------------------------------|----------------------|--------------------------|------------------------------|--------------|--------------|
| | | | | @RF0.9 (GHz) ^{Note} | @RF1.9 (GHz) | @RF2.4 (GHz) |
| μPC8172TK | 6-pin lead-less minimold | 9.0 | 0.8 to 2.5 | 9.5 | 8.5 | 8.0 |
| μPC8106TB | 6-pin super minimold (1511) | 9.0 | 0.4 to 2.0 | 9.0 | 7.0 | – |
| μPC8109TB | | 5.0 | 0.4 to 2.0 | 6.0 | 4.0 | – |
| μPC8163TB | | 16.5 | 0.8 to 2.0 | 9.0 | 5.5 | – |
| μPC8172TB | | 9.0 | 0.8 to 2.5 | 9.5 | 8.5 | 8.0 |
| μPC8187TB | | 15.0 | 0.8 to 2.5 | 11.0 | 11.0 | 10.0 |

| Part No. | P _{O (sat)} (dBm) | | | OIP ₃ (dBm) | | |
|-----------|------------------------------|--------------|--------------|------------------------------|--------------|--------------|
| | @RF0.9 (GHz) ^{Note} | @RF1.9 (GHz) | @RF2.4 (GHz) | @RF0.9 (GHz) ^{Note} | @RF1.9 (GHz) | @RF2.4 (GHz) |
| μPC8172TK | +0.5 | 0 | –0.5 | +7.5 | +6.0 | +4.0 |
| μPC8106TB | –2.0 | –4.0 | – | +5.5 | +2.0 | – |
| μPC8109TB | –5.5 | –7.5 | – | +1.5 | –1.0 | – |
| μPC8163TB | +0.5 | –2.0 | – | +9.5 | +6.0 | – |
| μPC8172TB | +0.5 | 0 | –0.5 | +7.5 | +6.0 | +4.0 |
| μPC8187TB | +4.0 | +2.5 | +1.0 | +10.0 | +10.0 | +8.5 |

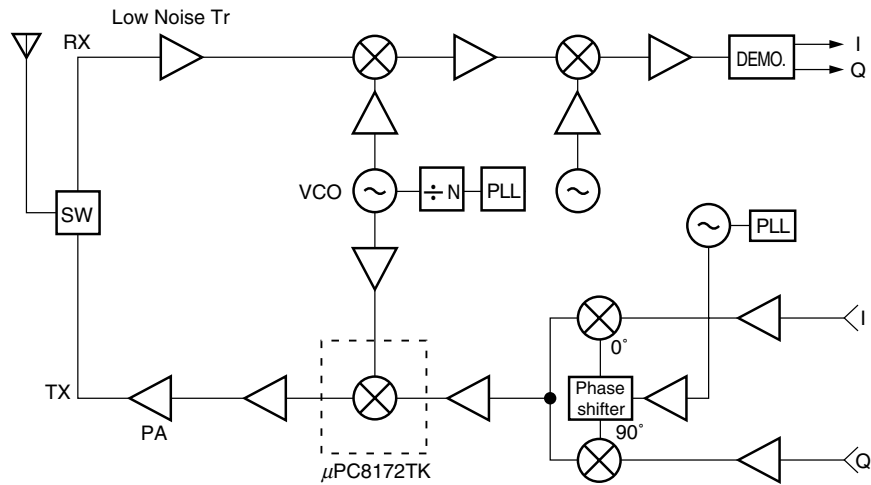
Note f_{RFout} = 0.83 GHz @ μPC8163TB, μPC8187TB

- Remarks**
1. Typical performance. Please refer to **ELECTRICAL CHARACTERISTICS** in detail.
 2. To know the associated product, please refer to each latest data sheet.

3. BLOCK DIAGRAM



4. SYSTEM APPLICATION EXAMPLE



Caution To know the associated products, please refer to each latest data sheet.

5. PIN EXPLANATION

| Pin No. | Pin Name | Applied Voltage (V) | Pin Voltage (V) ^{Note} | Function and Applications | Internal Equivalent Circuit | | | | | |
|-----------------|-----------------|--|---------------------------------|--|-----------------------------|----------|---------|-----------------|-----------|-----|
| 1 | IFinput | – | 1.3 | This pin is IF input to double balanced mixer (DBM). The input is designed as high impedance. The circuit contributes to suppress spurious signal. Also this symmetrical circuit can keep specified performance insensitive to process-condition distribution. For above reason, double balanced mixer is adopted. | | | | | | |
| 2 | GND | GND | – | GND pin. Ground pattern on the board should be formed as wide as possible. Track Length should be kept as short as possible to minimize ground impedance. | | | | | | |
| 3 | LOinput | – | 2.4 | Local input pin. Recommendable input level is –10 to 0 dBm. | | | | | | |
| 5 | V _{CC} | 2.7 to 3.3 | – | Supply voltage pin. | | | | | | |
| 6 | RFoutput | Same bias as V _{CC} through external inductor | – | This pin is RF output from DBM. This pin is designed as open collector. Due to the high impedance output, this pin should be externally equipped with LC matching circuit to next stage. | | | | | | |
| 4 | PS | V _{CC} /GND | – | Power save control pin. Bias controls operation as follows. <table border="1" style="margin: 10px auto;"> <thead> <tr> <th>Pin bias</th> <th>Control</th> </tr> </thead> <tbody> <tr> <td>V_{CC}</td> <td>Operation</td> </tr> <tr> <td>GND</td> <td>Power Save</td> </tr> </tbody> </table> | | Pin bias | Control | V _{CC} | Operation | GND |
| Pin bias | Control | | | | | | | | | |
| V _{CC} | Operation | | | | | | | | | |
| GND | Power Save | | | | | | | | | |

Note Each pin voltage is measured with V_{CC} = V_{PS} = V_{RFout} = 3.0 V

6. ABSOLUTE MAXIMUM RATINGS

| Parameter | Symbol | Test Conditions | Ratings | Unit |
|-------------------------------|------------------|------------------------------------|-------------|------|
| Supply Voltage | V _{CC} | T _A = +25°C | 3.6 | V |
| PS pin input Voltage | V _{PS} | T _A = +25°C | 3.6 | V |
| Power Dissipation of Package | P _D | T _A = +85°C Note | 203 | mW |
| Operating Ambient Temperature | T _A | | -40 to +85 | °C |
| Storage Temperature | T _{stg} | | -55 to +150 | °C |
| Input Power | P _{in} | | +10 | dBm |

Note Mounted on double-side copper-clad 50 × 50 × 1.6 mm epoxy glass PWB

7. RECOMMENDED OPERATING RANGE

| Parameter | Symbol | MIN. | TYP. | MAX. | Unit | Remarks |
|-------------------------------|--------------------|------|------|------|------|--|
| Supply Voltage | V _{CC} | 2.7 | 3.0 | 3.3 | V | Same voltage should be applied to pin 5 and pin 6. |
| Operating Ambient Temperature | T _A | -40 | +25 | +85 | °C | |
| Local Input Level | P _{LOin} | -10 | -5 | 0 | dBm | Z _s = 50 Ω (without matching) |
| RF Output Frequency | f _{RFout} | 0.8 | - | 2.5 | GHz | With external matching circuit |
| IF Input Frequency | f _{IFin} | 50 | - | 600 | MHz | |

8. ELECTRICAL CHARACTERISTICS (T_A = +25°C, V_{CC} = V_{RFout} = 3.0 V, f_{IFin} = 240 MHz, P_{LOin} = -5 dBm, and V_{PS} ≥ 2.7 V, unless otherwise specified)

| Parameter | Symbol | Test Conditions | MIN. | TYP. | MAX. | Unit | |
|------------------------------------|-----------------------|---|--|------|------|------|-----|
| Circuit Current | I _{CC} | No signal | 5.5 | 9.0 | 13 | mA | |
| Circuit Current In Power Save Mode | I _{CC(PS)} | V _{PS} = 0 V | - | - | 2.0 | μA | |
| Conversion Gain | CG1 | f _{RFout} = 0.9 GHz ^{Note1} | P _{IFin} = -30 dBm f _{IFin} = 240 MHz | 6.5 | 9.5 | 12.5 | dB |
| | CG2 | f _{RFout} = 1.9 GHz ^{Note2} | | 5.5 | 8.5 | 11.5 | dB |
| | CG3 | f _{RFout} = 2.4 GHz ^{Note2} | | 5.0 | 8.0 | 11.0 | dB |
| Saturated RF output Power | P _{O(sat) 1} | f _{RFout} = 0.9 GHz ^{Note1} | P _{IFin} = 0 dBm f _{IFin} = 240 MHz | -2.5 | +0.5 | - | dBm |
| | P _{O(sat) 2} | f _{RFout} = 1.9 GHz ^{Note2} | | -3.5 | 0 | - | dBm |
| | P _{O(sat) 3} | f _{RFout} = 2.4 GHz ^{Note2} | | -4.0 | -0.5 | - | dBm |

Notes 1. f_{RFout} < f_{LOin} @ f_{RFout} = 0.9 GHz

2. f_{LOin} < f_{RFout} @ f_{RFout} = 1.9 GHz/2.4 GHz

9. OTHER CHARACTERISTICS, FOR REFERENCE PURPOSES ONLY

($T_A = +25^\circ\text{C}$, $V_{CC} = V_{RFout} = 3.0\text{ V}$, $PL_{Oin} = -5\text{ dBm}$, and $V_{PS} \geq 2.7\text{ V}$, unless otherwise specified)

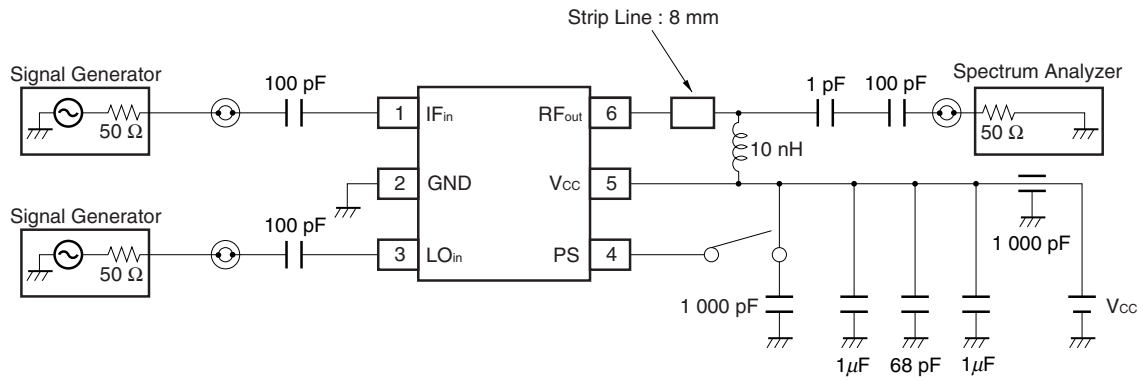
| Parameter | | Symbol | Test Conditions | Data | Unit | |
|---|-----------|--------------------|--|--|------|-----|
| Output 3rd Order Distortion Intercept Point | | OIP ₃ 1 | $f_{RFout} = 0.9\text{ GHz}$ ^{Note1} | $f_{IFin1} = 240\text{ MHz}$ $f_{IFin2} = 241\text{ MHz}$ | +7.5 | dBm |
| | | OIP ₃ 2 | $f_{RFout} = 1.9\text{ GHz}$ ^{Note2} | | +6.0 | dBm |
| | | OIP ₃ 3 | $f_{RFout} = 2.4\text{ GHz}$ ^{Note2} | | +4.0 | dBm |
| Input 3rd Order Distortion Intercept Point | | IIP ₃ 1 | $f_{RFout} = 0.9\text{ GHz}$ ^{Note1} | $f_{IFin1} = 240\text{ MHz}$ $f_{IFin2} = 241\text{ MHz}$ | -2.0 | dBm |
| | | IIP ₃ 2 | $f_{RFout} = 1.9\text{ GHz}$ ^{Note2} | | -2.5 | dBm |
| | | IIP ₃ 3 | $f_{RFout} = 2.4\text{ GHz}$ ^{Note2} | | -4.0 | dBm |
| SSB Noise Figure | | SSB-NF1 | $f_{RFout} = 0.9\text{ GHz}$, $f_{IFin} = 240\text{ MHz}$ | 9.5 | dB | |
| | | SSB-NF2 | $f_{RFout} = 1.9\text{ GHz}$, $f_{IFin} = 240\text{ MHz}$ | 10.4 | dB | |
| | | SSB-NF3 | $f_{RFout} = 2.4\text{ GHz}$, $f_{IFin} = 240\text{ MHz}$ | 10.6 | dB | |
| Power Save Response Time | Rise time | $T_{PS (rise)}$ | $V_{PS} : \text{GND} \rightarrow V_{CC}$ | 1.0 | μs | |
| | Fall time | $T_{PS (fall)}$ | $V_{PS} : V_{CC} \rightarrow \text{GND}$ | 1.5 | μs | |

Notes1. $f_{RFout} < f_{LOin}$ @ $f_{RFout} = 0.9\text{ GHz}$

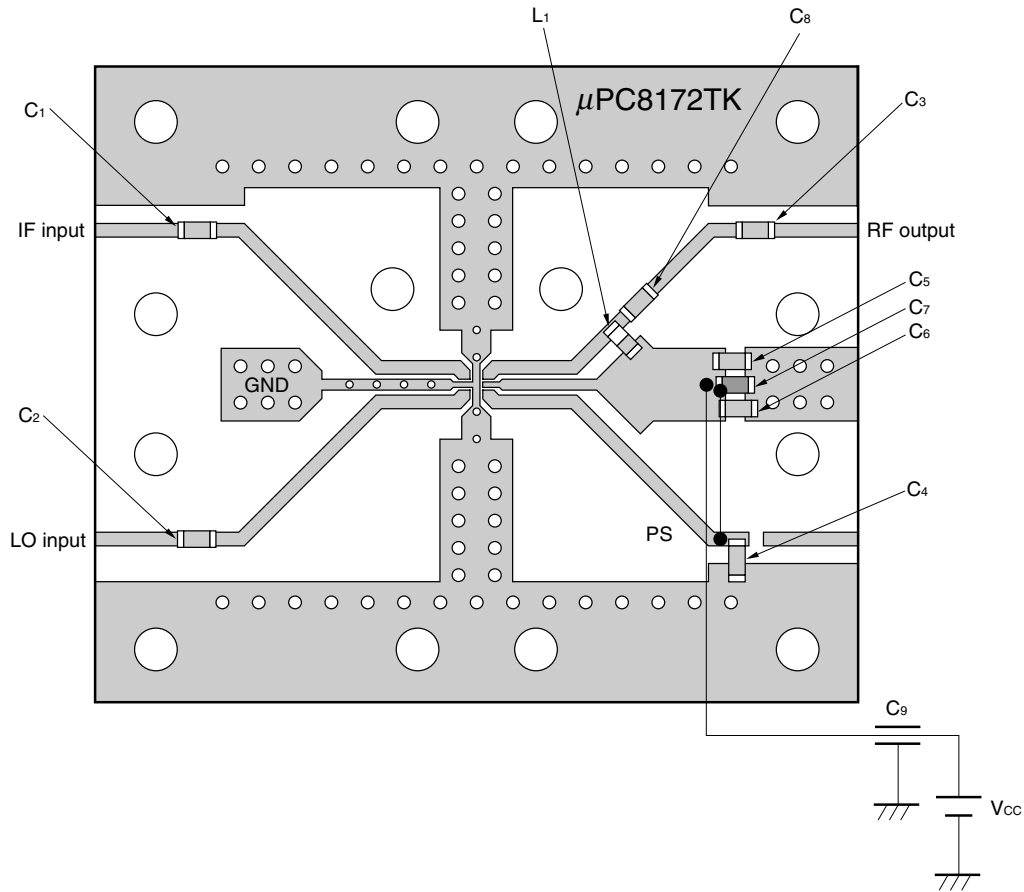
2. $f_{LOin} < f_{RFout}$ @ $f_{RFout} = 1.9\text{ GHz}/2.4\text{ GHz}$

★ 10. TEST CIRCUIT

10.1 TEST CIRCUIT 1 ($f_{RFout} = 0.9\text{ GHz}$)



EXAMPLE OF TEST CIRCUIT 1 ASSEMBLED ON EVALUATION BOARD

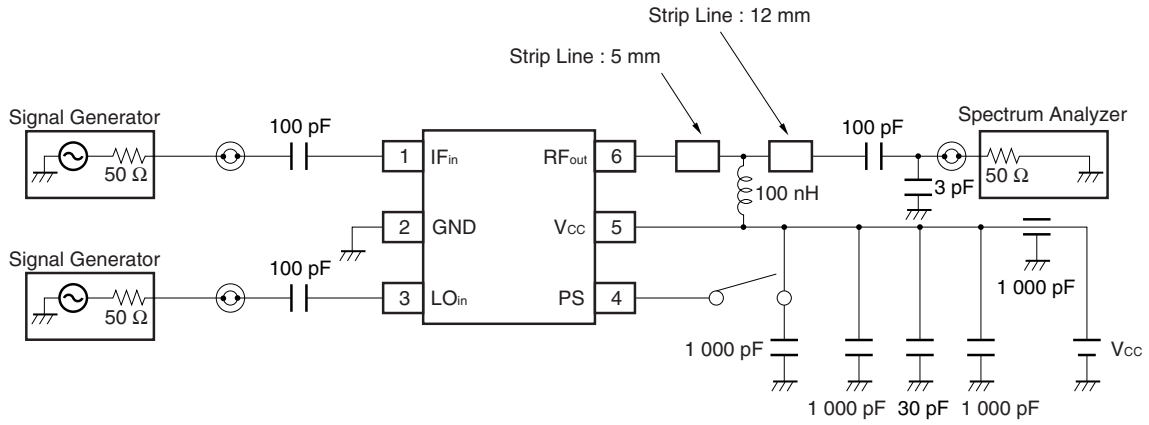


COMPONENT LIST

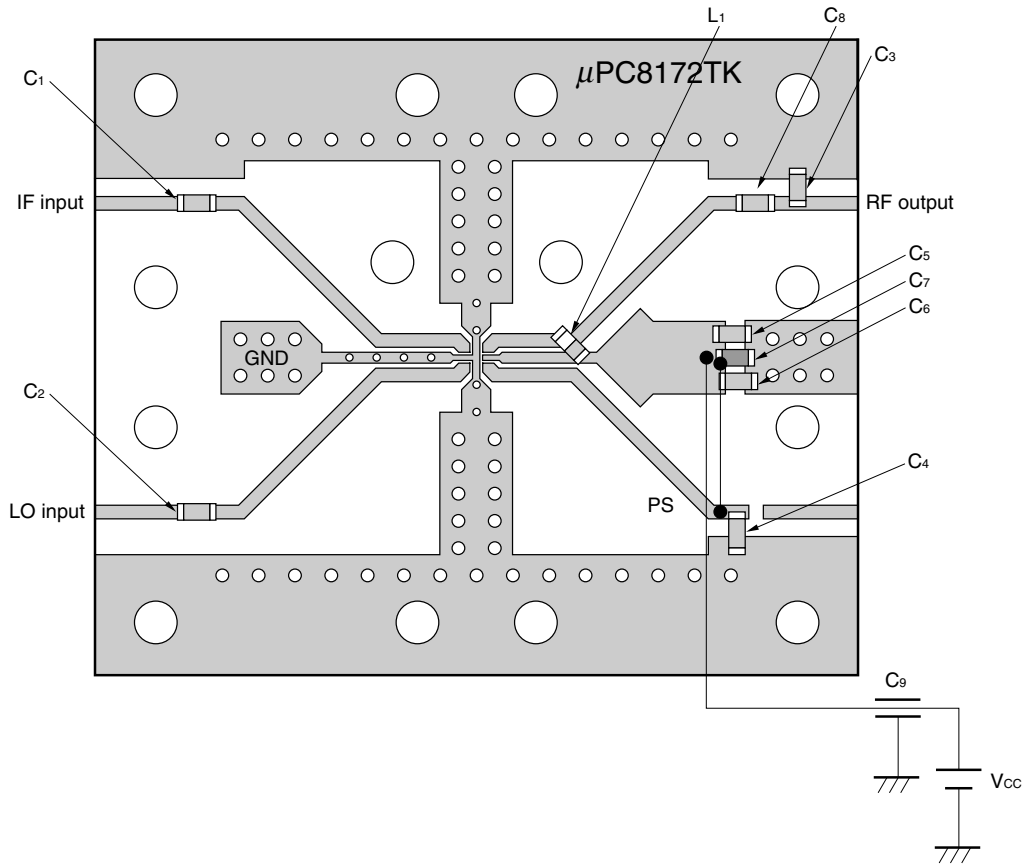
| Form | Symbol | Value | Type code | Maker |
|------------------------|--|----------|-----------------------|--------|
| Chip capacitor | C ₁ , C ₂ , C ₃ | 100 pF | GRM39CH101J50PT | murata |
| | C ₄ | 1 000 pF | GRM39B102K50PT | murata |
| | C ₅ , C ₆ | 1 μF | GRM39F105Z10PT | murata |
| | C ₇ | 68 pF | GRM39CH680J50PT | murata |
| | C ₈ | 1 pF | GRM39CH010C50PT | murata |
| Feed-through Capacitor | C ₉ | 1 000 pF | DFT301-801 × 7R102S50 | murata |
| Chip inductor | L ₁ | 10 nH | LL1608-F10N | TOKO |

- (*1) 35 × 42 × 0.4 mm polyimide board, double-sided copper clad
- (*2) Ground pattern on rear of the board
- (*3) Solder plated patterns
- (*4) ○○○: Through holes

10.2 TEST CIRCUIT 2 ($f_{RFout} = 1.9\text{ GHz}$)



EXAMPLE OF TEST CIRCUIT 2 ASSEMBLED ON EVALUATION BOARD



COMPONENT LIST

| Form | Symbol | Value | Type code | Maker |
|------------------------|--|----------|-----------------------|--------|
| Chip capacitor | C ₁ , C ₂ , C ₃ | 100 pF | GRM39CH101J50PT | murata |
| | C ₄ , C ₅ , C ₆ | 1 000 pF | GRM39B102K50PT | murata |
| | C ₇ | 30 pF | GRM39CH300J50PT | murata |
| | C ₈ | 3 pF | GRM39CH030C50PT | murata |
| Feed-through Capacitor | C ₉ | 1 000 pF | DFT301-801 × 7R102S50 | murata |
| Chip inductor | L ₁ | 100 nH | LL1608-FR10 | TOKO |

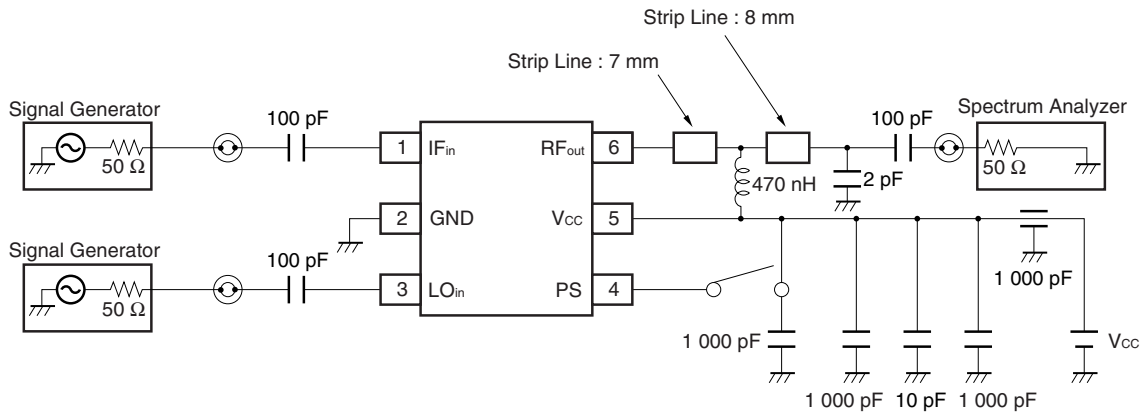
(*1) 35 × 42 × 0.4 mm polyimide board, double-sided copper clad

(*2) Ground pattern on rear of the board

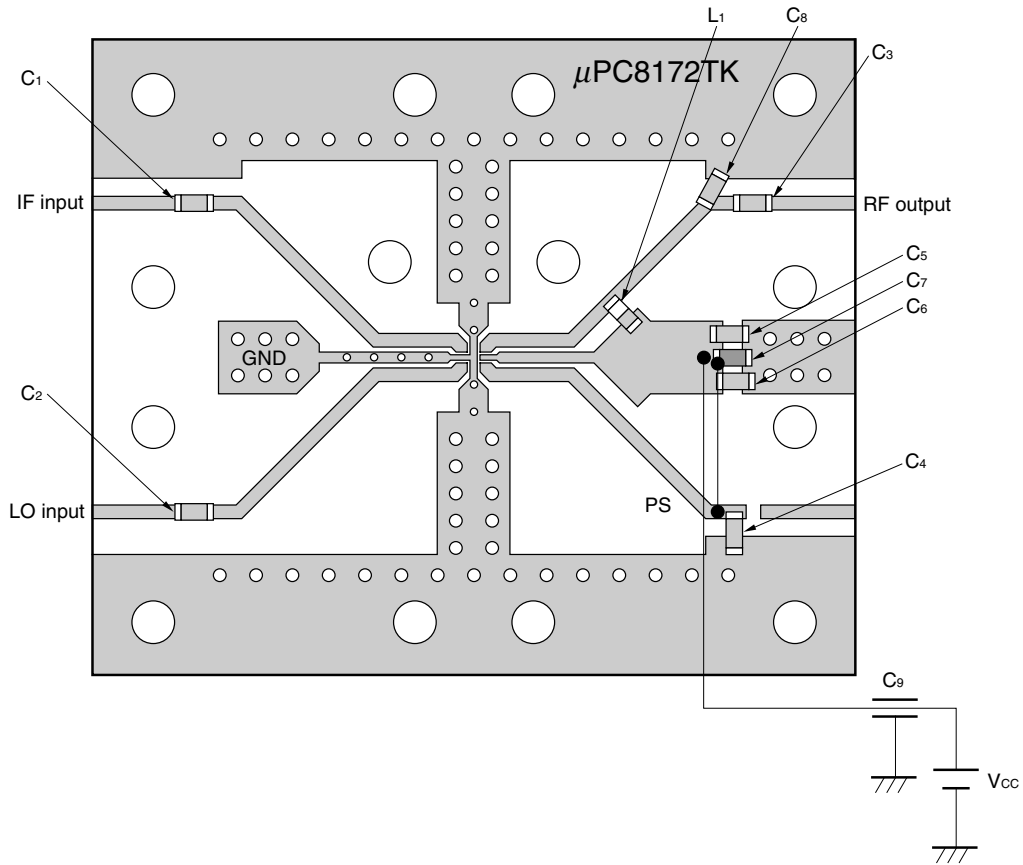
(*3) Solder plated patterns

(*4) ○○: Through holes

10.3 TEST CIRCUIT 3 ($f_{RFout} = 2.4\text{ GHz}$)



EXAMPLE OF TEST CIRCUIT 3 ASSEMBLED ON EVALUATION BOARD



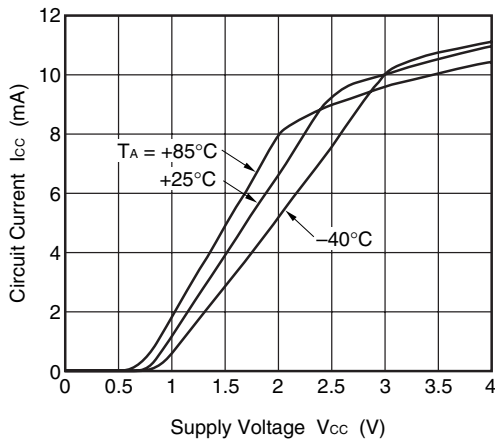
COMPONENT LIST

| Form | Symbol | Value | Type code | Maker |
|------------------------|--|----------|-----------------------|--------|
| Chip capacitor | C ₁ , C ₂ , C ₃ | 100 pF | GRM39CH101J50PT | murata |
| | C ₄ , C ₅ , C ₆ | 1 000 pF | GRM39B102K50PT | murata |
| | C ₇ | 10 pF | GRM39CH100D50PT | murata |
| | C ₈ | 2 pF | GRM39CH020C50PT | murata |
| Feed-through Capacitor | C ₉ | 1 000 pF | DFT301-801 × 7R102S50 | murata |
| Chip inductor | L ₁ | 470 nH | LL2012-FR47 | TOKO |

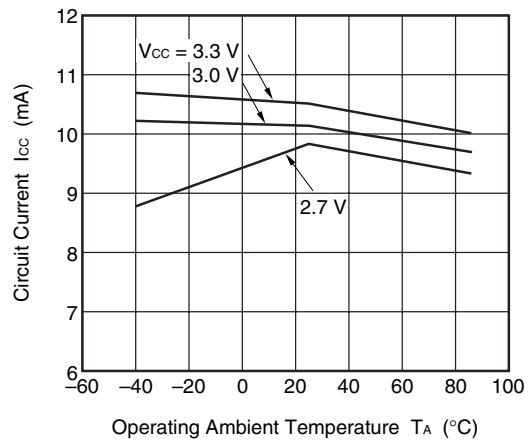
- (*1) 35 × 42 × 0.4 mm polyimide board, double-sided copper clad
- (*2) Ground pattern on rear of the board
- (*3) Solder plated patterns
- (*4) ○○○: Through holes

★ 11. TYPICAL CHARACTERISTICS ($T_A = +25^\circ\text{C}$, unless otherwise specified)

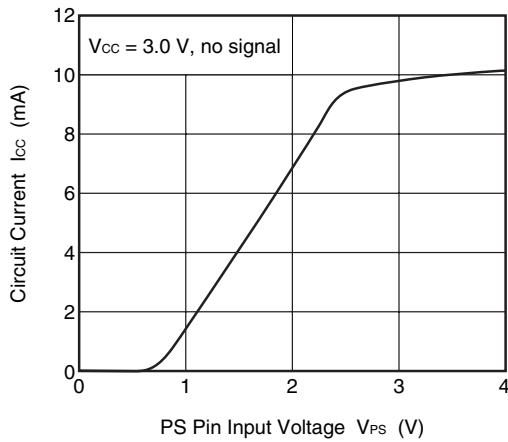
CIRCUIT CURRENT vs. SUPPLY VOLTAGE



CIRCUIT CURRENT vs. OPERATING AMBIENT TEMPERATURE



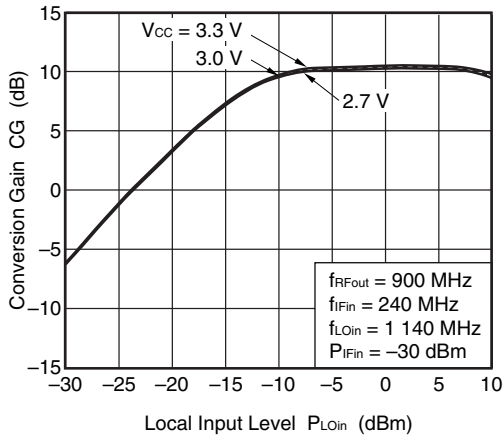
CIRCUIT CURRENT vs. PS PIN INPUT VOLTAGE



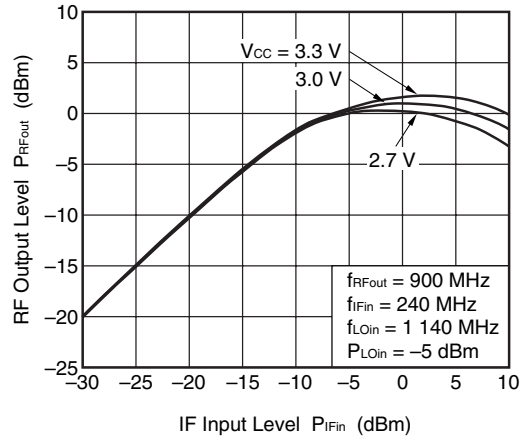
Remark The graphs indicate nominal characteristics.

11.1 $f_{RFout} = 900$ MHz MATCHING

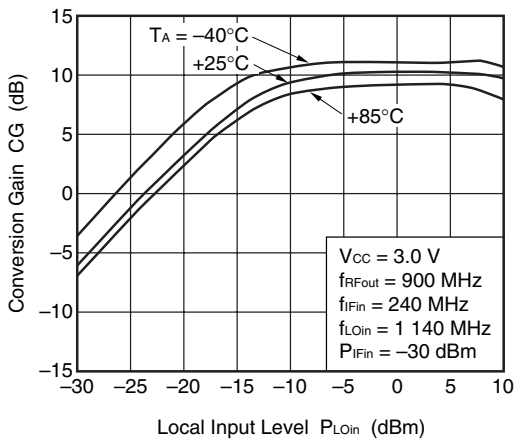
CONVERSION GAIN vs. LOCAL INPUT LEVEL



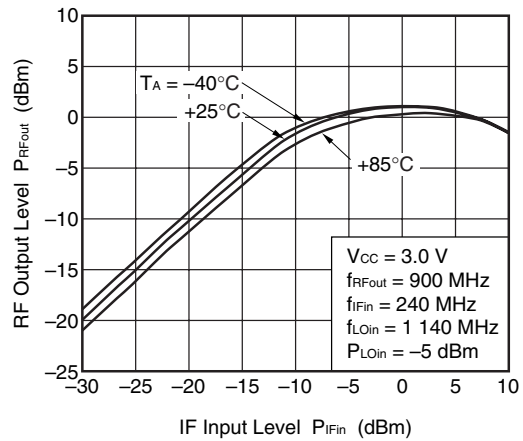
RF OUTPUT LEVEL vs. IF INPUT LEVEL



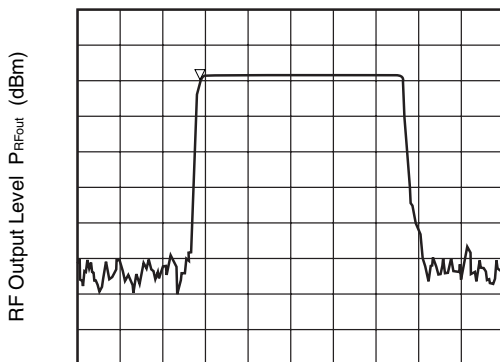
CONVERSION GAIN vs. LOCAL INPUT LEVEL



RF OUTPUT LEVEL vs. IF INPUT LEVEL



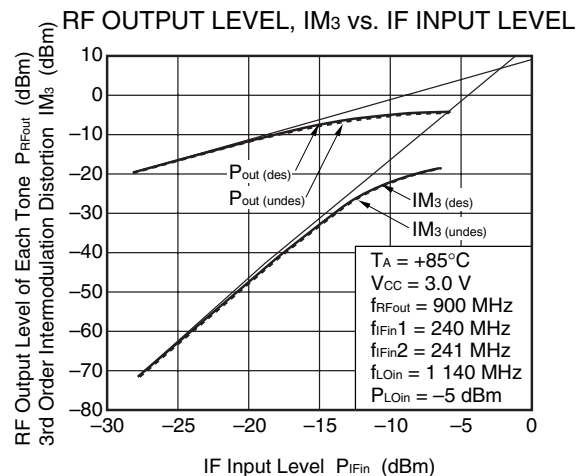
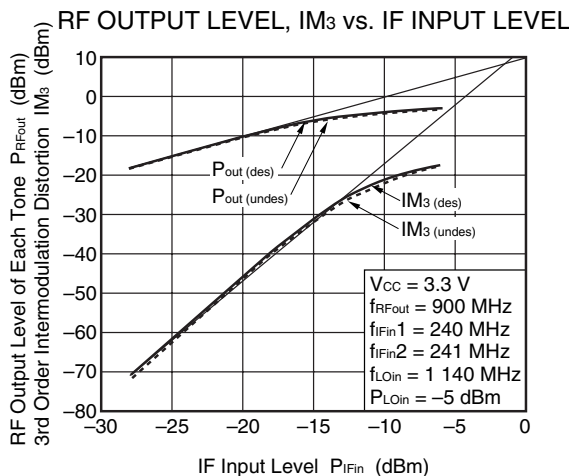
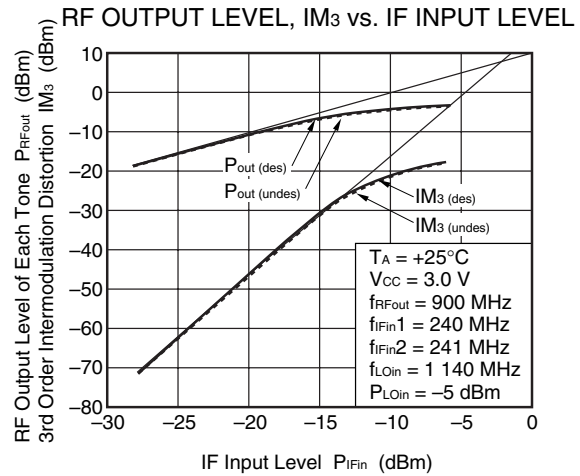
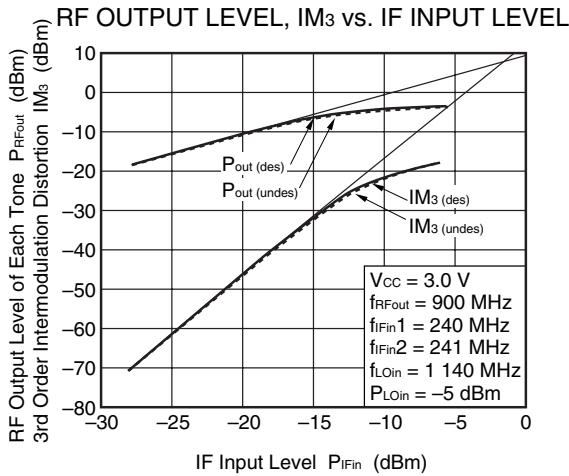
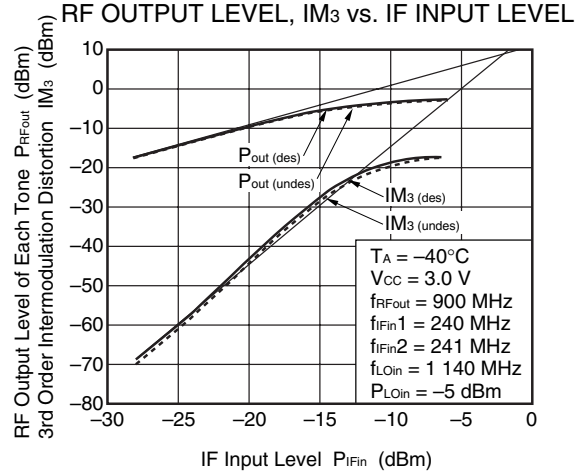
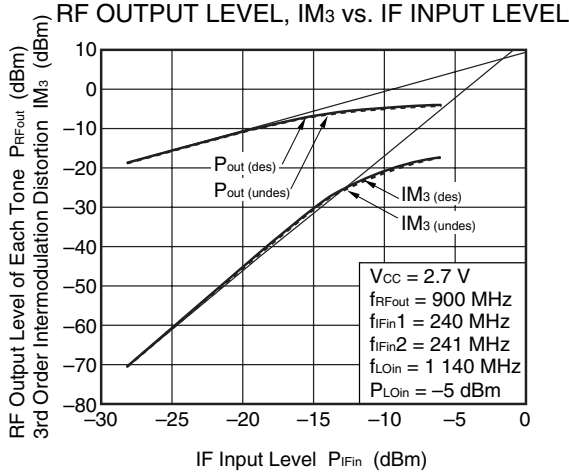
PS PIN CONTROL RESPONSE TIME



REF LVL = 0 dBm $V_{CC} = 3.0$ V
 10 dB/DIV (vertical axis) $f_{RFout} = 0.9$ GHz
 ATT = 10 dB $f_{IFin} = 240$ MHz
 CENTER = 0.9 GHz $P_{IFin} = -30$ dBm
 SPAN = 0 Hz $f_{LOin} = 1.140$ MHz
 RBW = 2 MHz $P_{LOin} = -5$ dBm
 VBW = 3 MHz $\Delta MKR = -20.0$ dBm, 14.7 μ s
 SWP = 50 μ sec
 5 μ sec/DIV (horizontal axis)

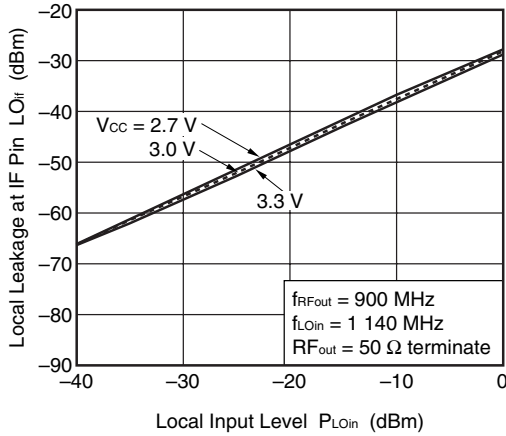
Response Time (μ s)

Remark The graphs indicate nominal characteristics.

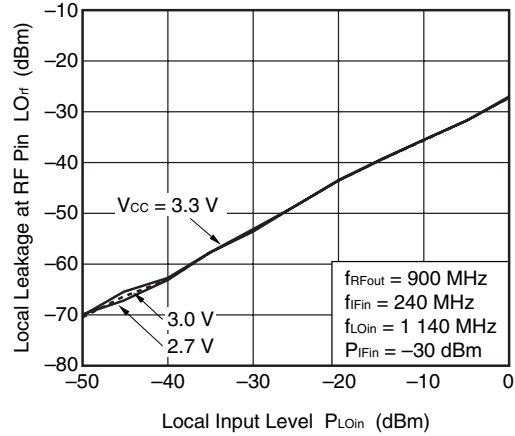


Remark The graphs indicate nominal characteristics.

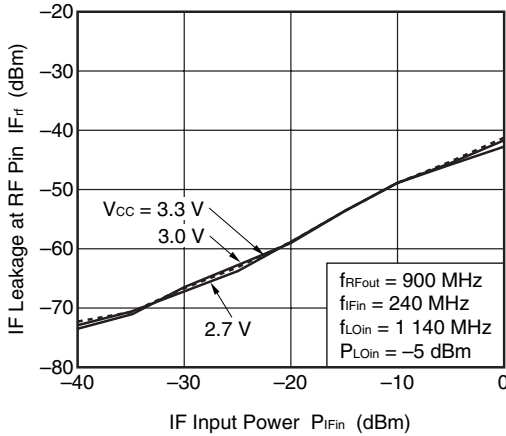
LOCAL LEAKAGE AT IF PIN vs. LOCAL INPUT LEVEL



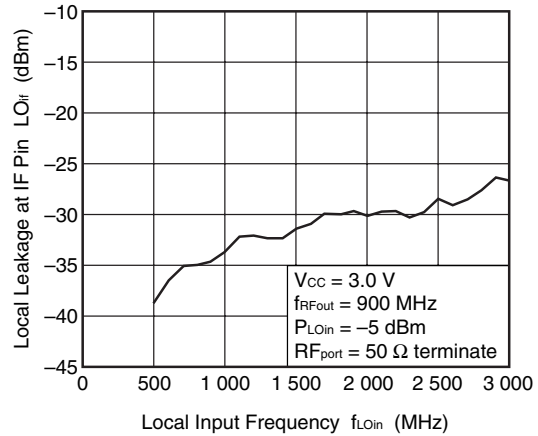
LOCAL LEAKAGE AT RF PIN vs. LOCAL INPUT LEVEL



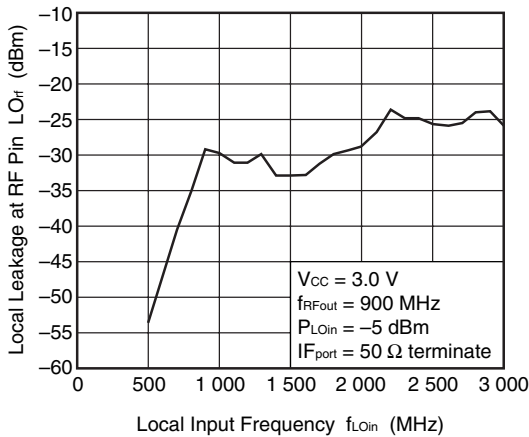
IF LEAKAGE AT RF PIN vs. IF INPUT POWER



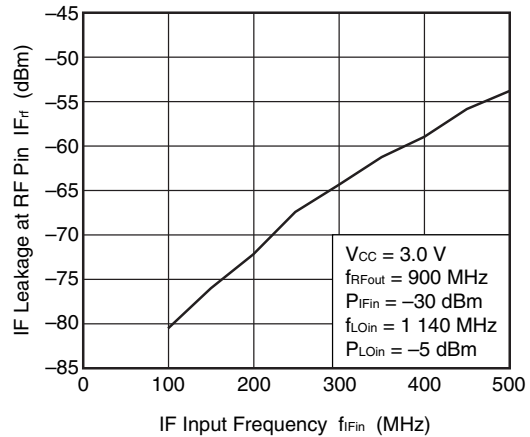
LOCAL LEAKAGE AT IF PIN vs. LOCAL INPUT FREQUENCY



LOCAL LEAKAGE AT RF PIN vs. LOCAL INPUT FREQUENCY

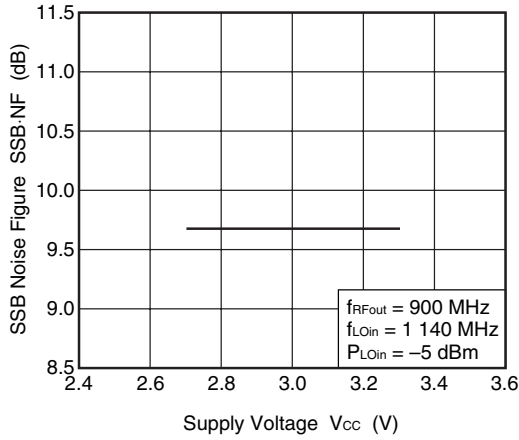


IF LEAKAGE AT RF PIN vs. IF INPUT FREQUENCY

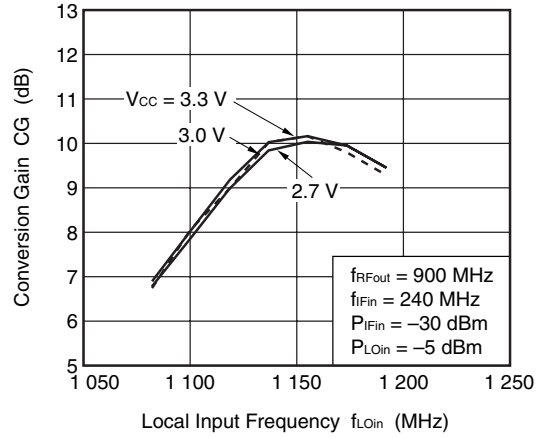


Remark The graphs indicate nominal characteristics.

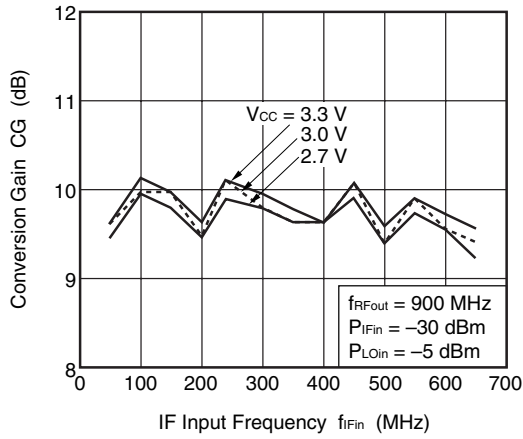
SSB NOISE FIGURE vs. SUPPLY VOLTAGE



CONVERSION GAIN vs. LOCAL INPUT FREQUENCY



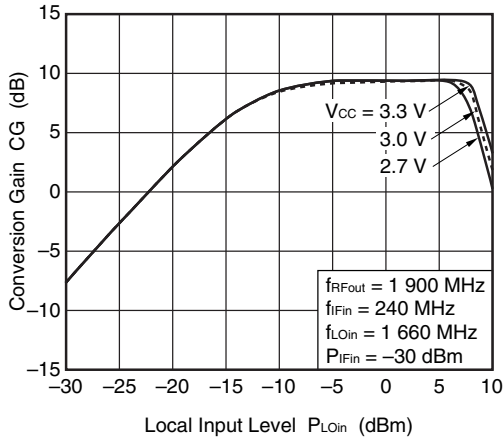
CONVERSION GAIN vs. IF INPUT FREQUENCY



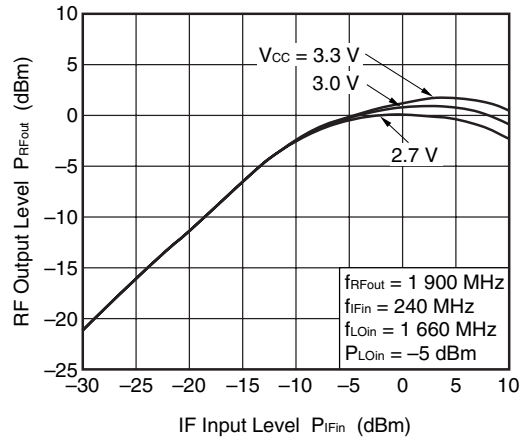
Remark The graphs indicate nominal characteristics.

11.2 $f_{RFout} = 1\ 900\ \text{MHz}$ MATCHING

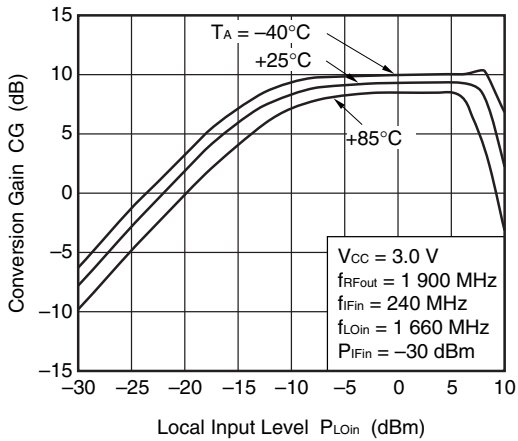
CONVERSION GAIN vs. LOCAL INPUT LEVEL



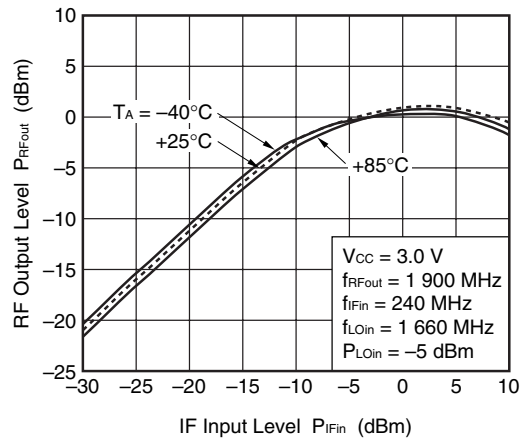
RF OUTPUT LEVEL vs. IF INPUT LEVEL



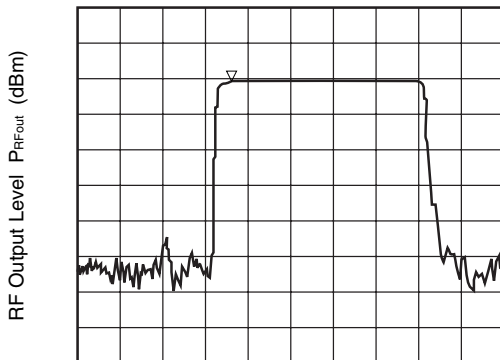
CONVERSION GAIN vs. LOCAL INPUT LEVEL



RF OUTPUT LEVEL vs. IF INPUT LEVEL



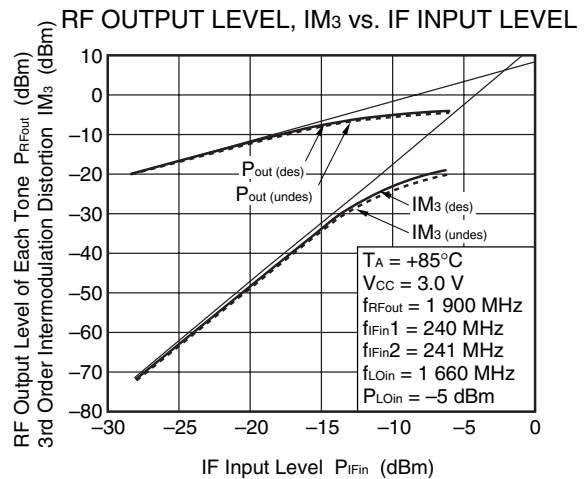
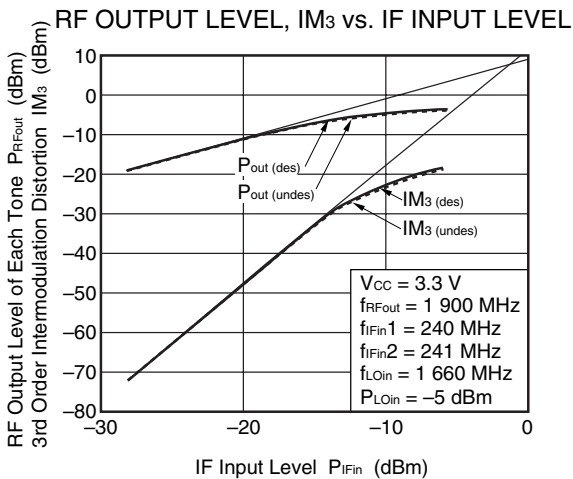
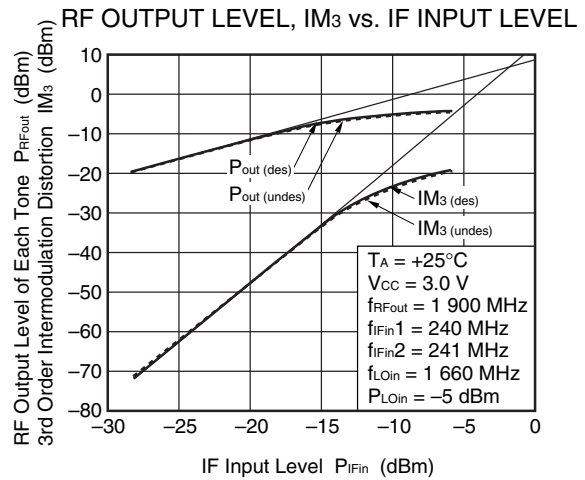
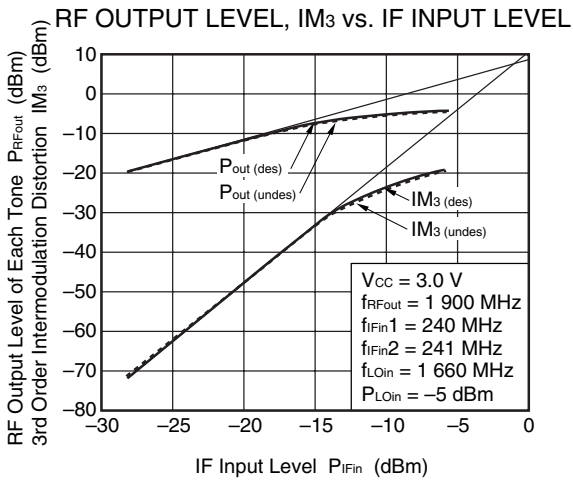
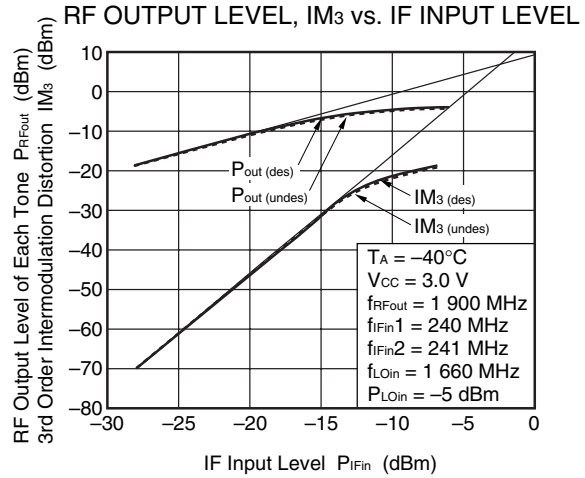
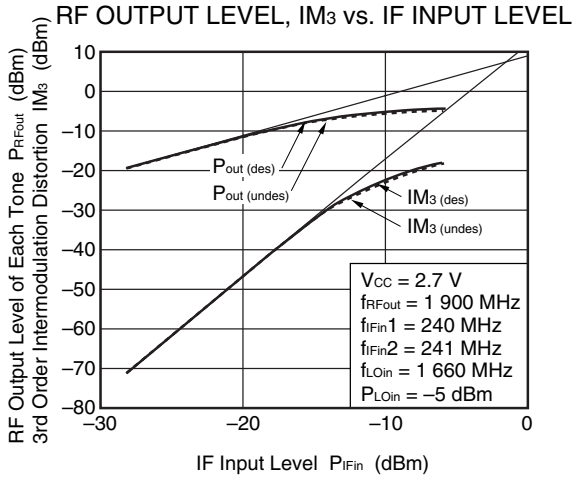
PS PIN CONTROL RESPONSE TIME



REF LVL = 0 dBm $V_{CC} = 3.0\ \text{V}$
 10 dB/DIV (vertical axis) $f_{RFout} = 1.9\ \text{GHz}$
 ATT = 10 dB $f_{IFin} = 240\ \text{MHz}$
 CENTER = 1.9 GHz $P_{IFin} = -30\ \text{dBm}$
 SPAN = 0 Hz $f_{LOin} = 1\ 660\ \text{MHz}$
 RBW = 2 MHz $P_{LOin} = -5\ \text{dBm}$
 VBW = 3 MHz $\Delta\text{MKR} = -21.0\ \text{dBm}, 17.9\ \mu\text{s}$
 SWP = 50 μsec
 5 μsec /DIN (horizontal axis)

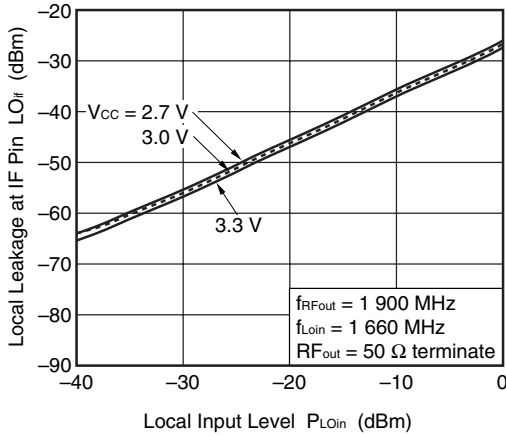
Response Time (μs)

Remark The graphs indicate nominal characteristics.

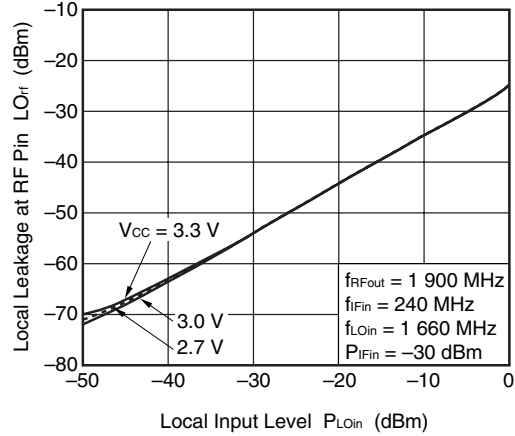


Remark The graphs indicate nominal characteristics.

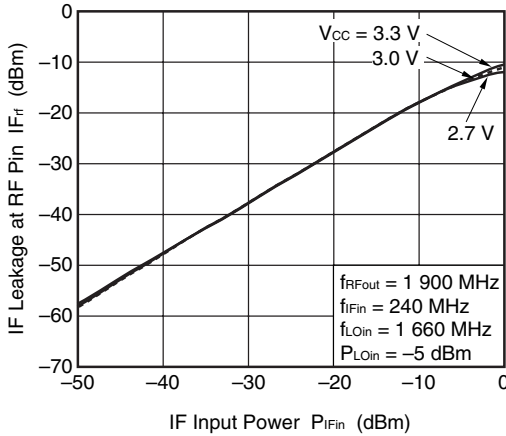
LOCAL LEAKAGE AT IF PIN
vs. LOCAL INPUT LEVEL



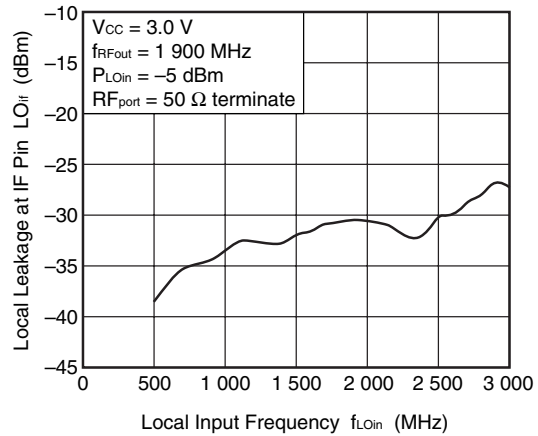
LOCAL LEAKAGE AT RF PIN
vs. LOCAL INPUT LEVEL



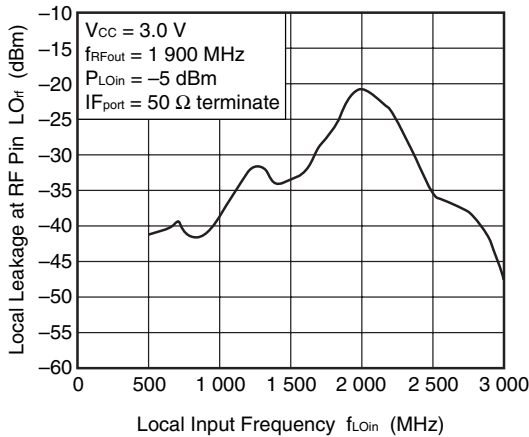
IF LEAKAGE AT RF PIN
vs. IF INPUT POWER



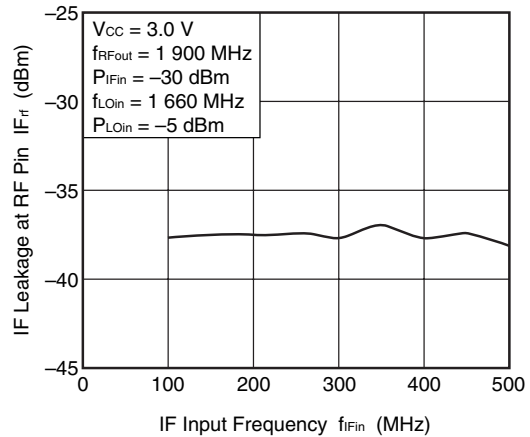
LOCAL LEAKAGE AT IF PIN
vs. LOCAL INPUT FREQUENCY



LOCAL LEAKAGE AT RF PIN
vs. LOCAL INPUT FREQUENCY

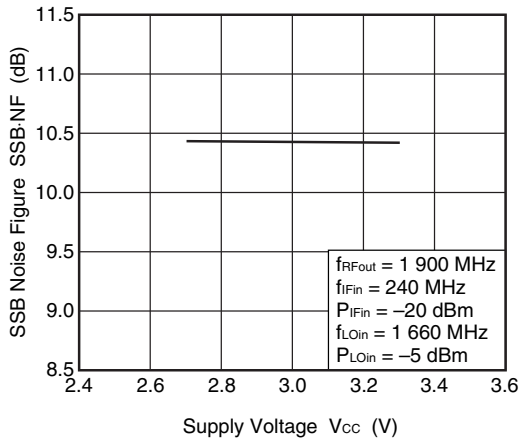


IF LEAKAGE AT RF PIN
vs. IF INPUT FREQUENCY

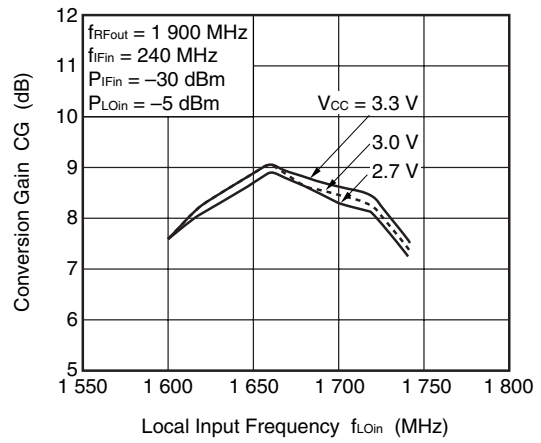


Remark The graphs indicate nominal characteristics.

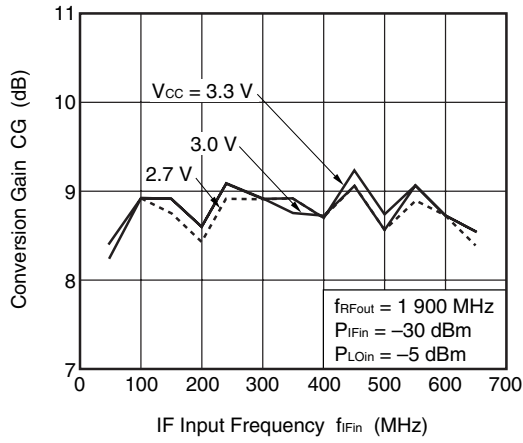
SSB NOISE FIGURE vs. SUPPLY VOLTAGE



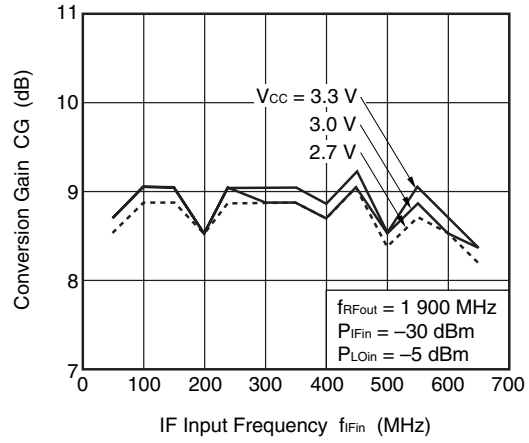
CONVERSION GAIN vs. LOCAL INPUT FREQUENCY



CONVERSION GAIN vs. IF INPUT FREQUENCY ($f_{LOin} < f_{RFout}$)



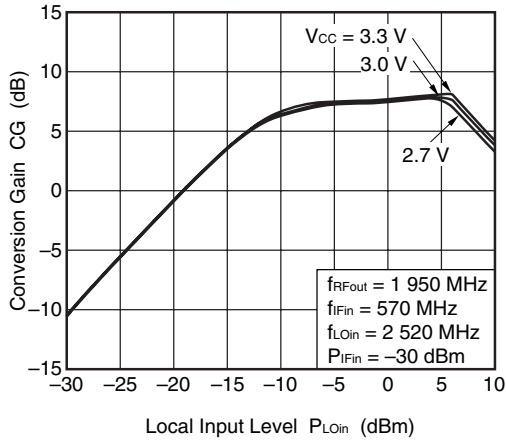
CONVERSION GAIN vs. IF INPUT FREQUENCY ($f_{LOin} > f_{RFout}$)



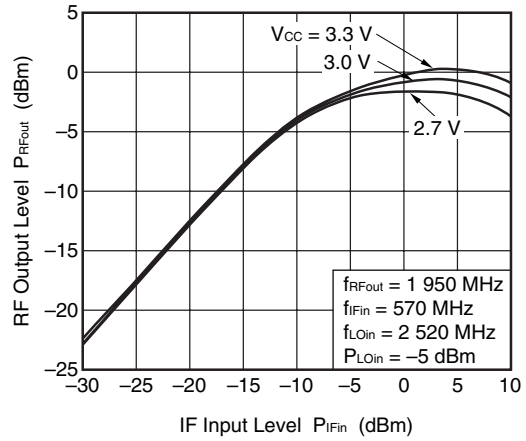
Remark The graphs indicate nominal characteristics.

11.3 $f_{RFout} = 1\ 950\ \text{MHz}$ MATCHING

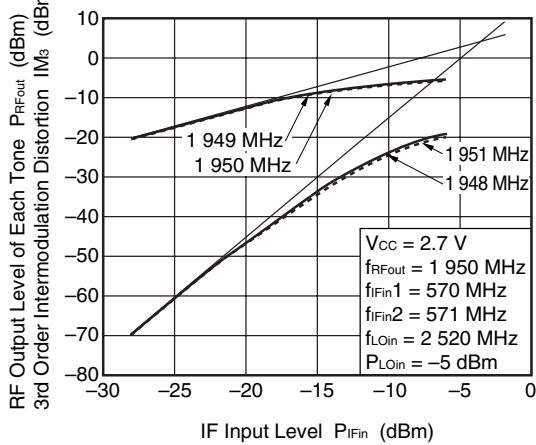
CONVERSION GAIN vs. LOCAL INPUT LEVEL



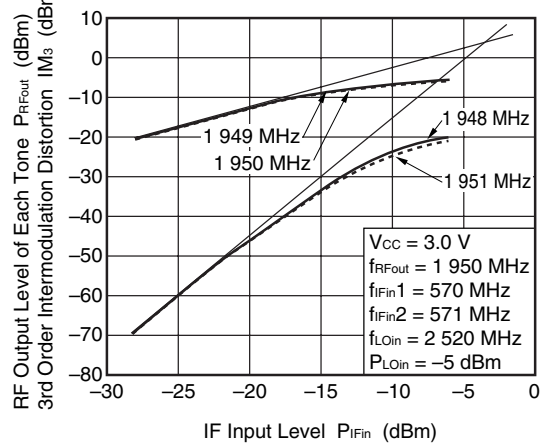
RF OUTPUT LEVEL vs. IF INPUT LEVEL



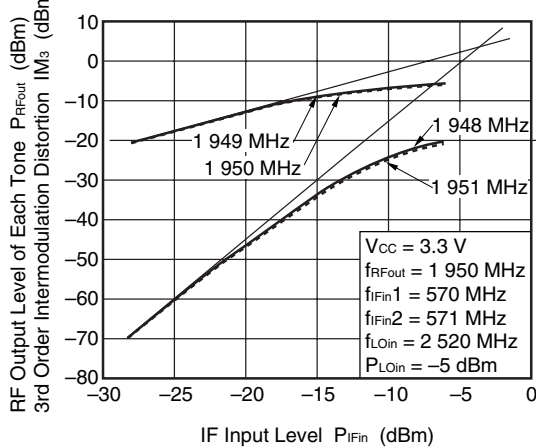
RF OUTPUT LEVEL, IM_3 vs. IF INPUT LEVEL



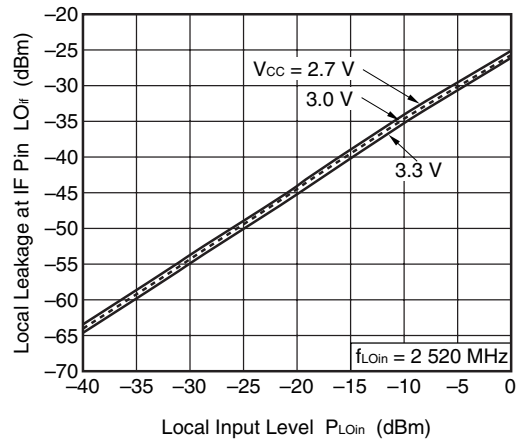
RF OUTPUT LEVEL, IM_3 vs. IF INPUT LEVEL



RF OUTPUT LEVEL, IM_3 vs. IF INPUT LEVEL

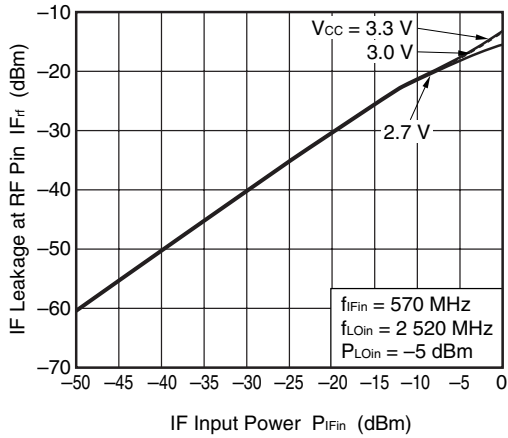


LOCAL LEAKAGE AT IF PIN vs. LOCAL INPUT LEVEL

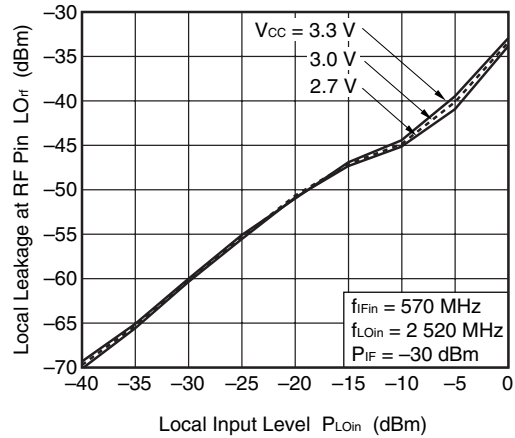


Remark The graphs indicate nominal characteristics.

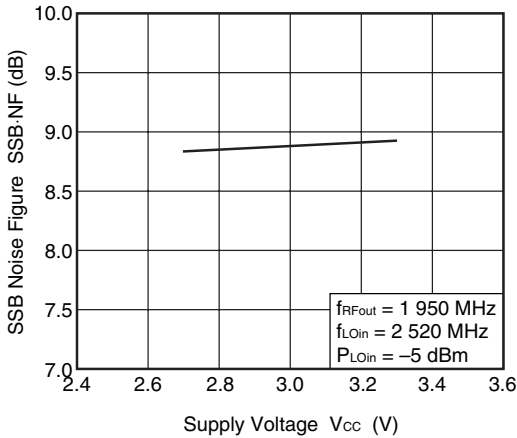
IF LEAKAGE AT RF PIN
vs. IF INPUT POWER



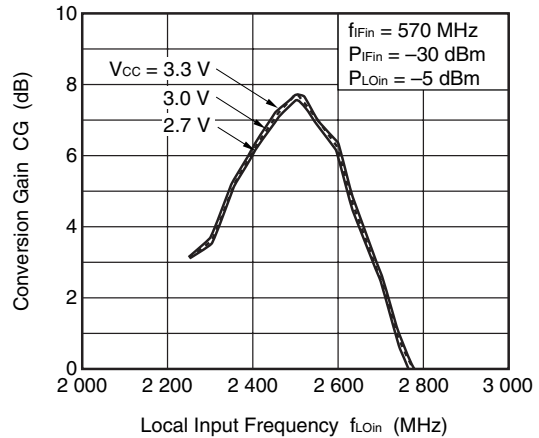
LOCAL LEAKAGE AT RF PIN
vs. LOCAL INPUT LEVEL



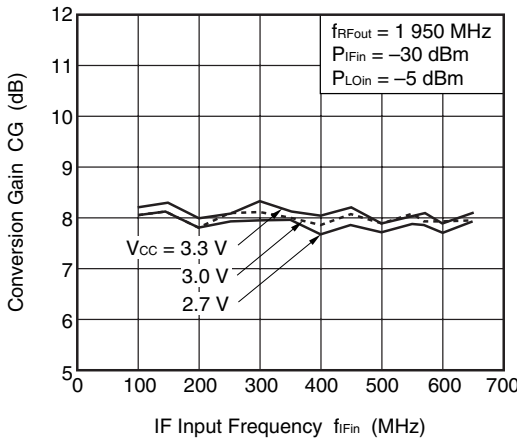
SSB NOISE FIGURE vs. SUPPLY VOLTAGE



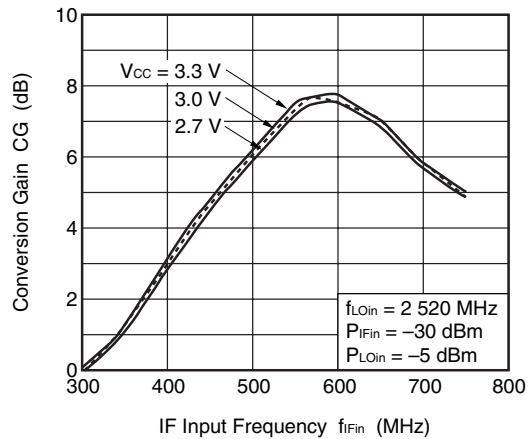
CONVERSION GAIN vs.
LOCAL INPUT FREQUENCY



CONVERSION GAIN vs.
IF INPUT FREQUENCY



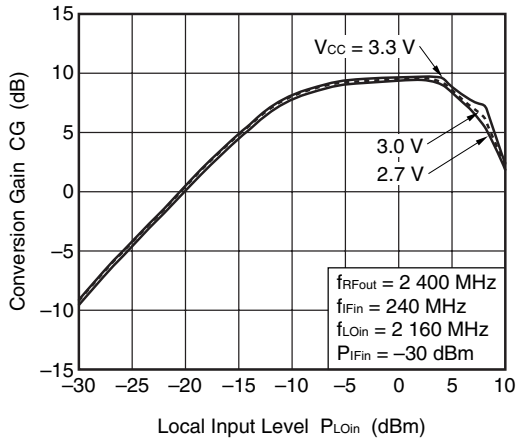
CONVERSION GAIN vs.
IF INPUT FREQUENCY



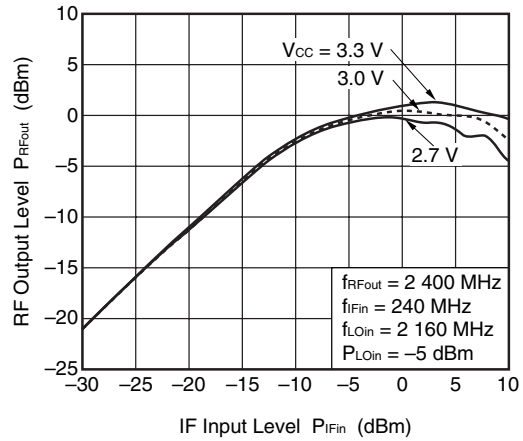
Remark The graphs indicate nominal characteristics.

11.4 $f_{RFout} = 2\ 400\ \text{MHz}$ MATCHING

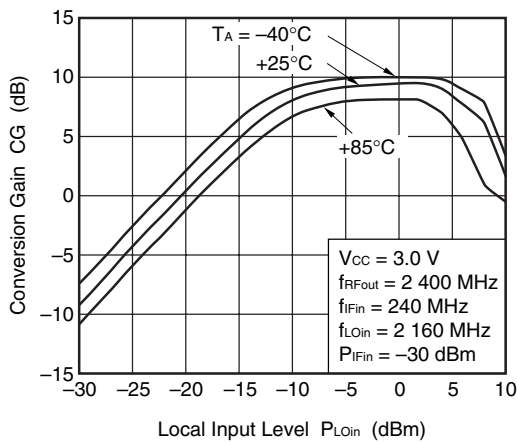
CONVERSION GAIN vs. LOCAL INPUT LEVEL



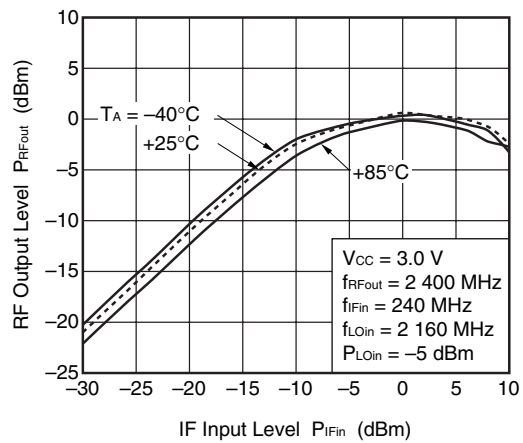
RF OUTPUT LEVEL vs. IF INPUT LEVEL



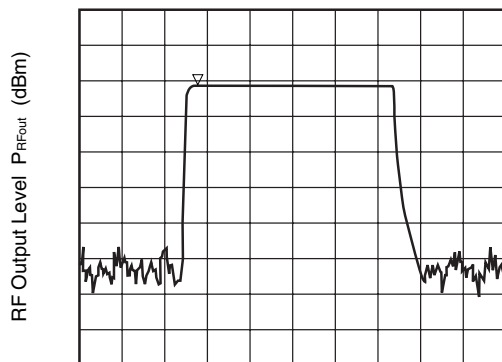
CONVERSION GAIN vs. LOCAL INPUT LEVEL



RF OUTPUT LEVEL vs. IF INPUT LEVEL



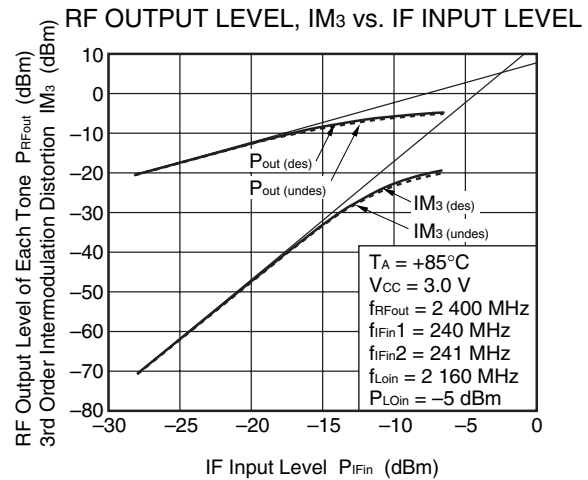
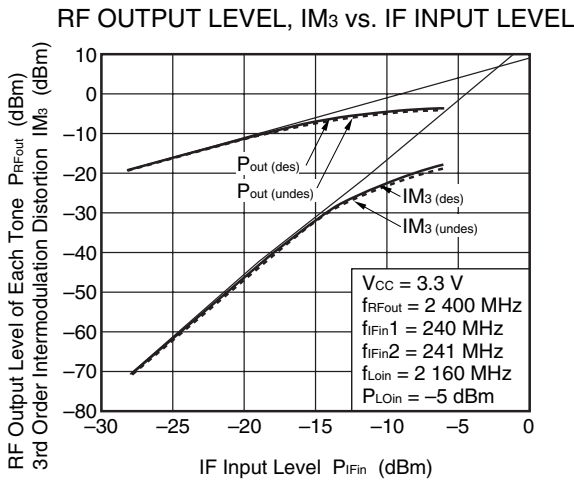
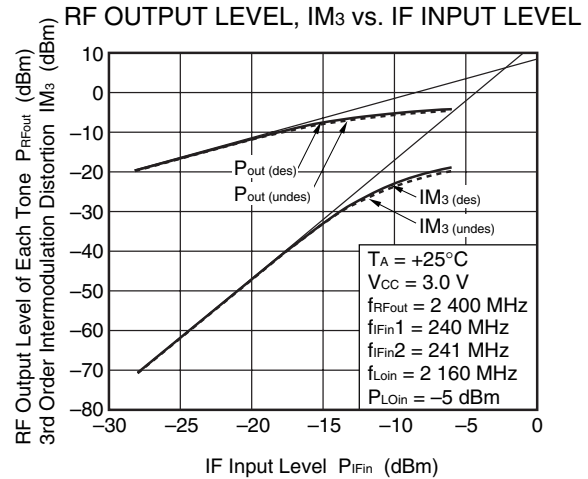
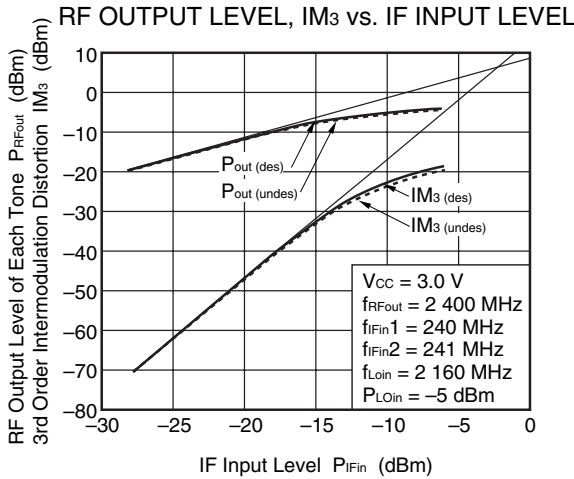
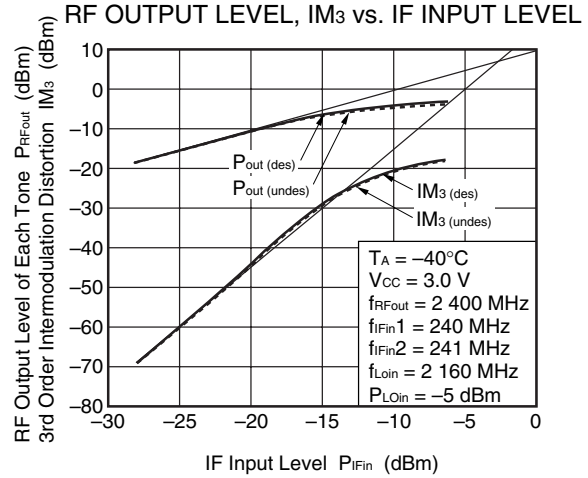
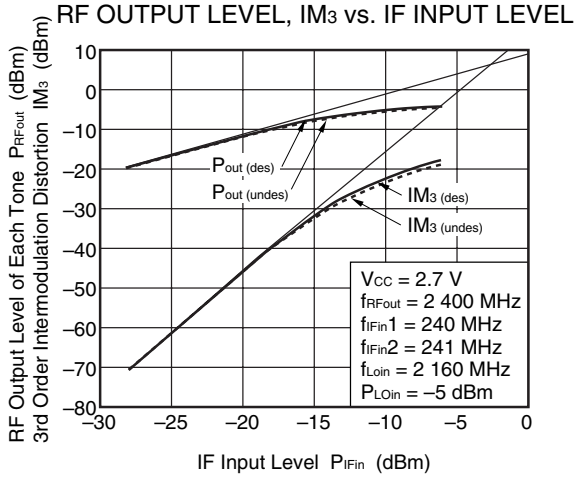
PS PIN CONTROL RESPONSE TIME



REF LVL = 0 dBm $V_{CC} = 3.0\ \text{V}$
 10 dB/DIV (vertical axis) $f_{RFout} = 2.4\ \text{GHz}$
 ATT = 10 dB $f_{Fin} = 240\ \text{MHz}$
 CENTER = 2.4 GHz $P_{Fin} = -30\ \text{dBm}$
 SPAN = 0 Hz $f_{LOin} = 2\ 160\ \text{MHz}$
 RBW = 2 MHz $P_{LOin} = -5\ \text{dBm}$
 VBW = 3 MHz $\Delta\text{MKR} = -21.5\ \text{dBm}, 13.8\ \mu\text{s}$
 SWP = 50 μsec
 5 $\mu\text{sec}/\text{DIN}$ (horizontal axis)

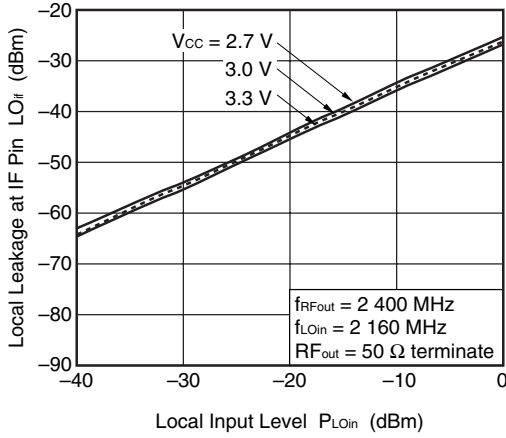
Response Time (μs)

Remark The graphs indicate nominal characteristics.

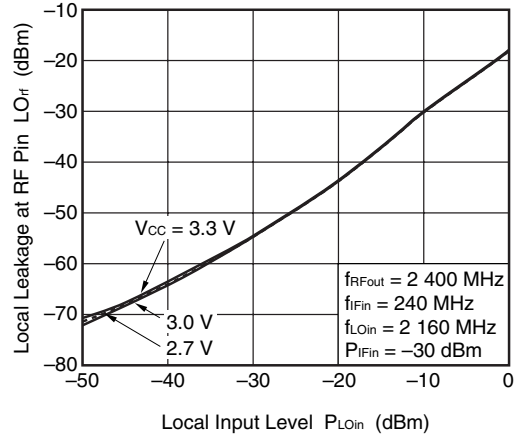


Remark The graphs indicate nominal characteristics.

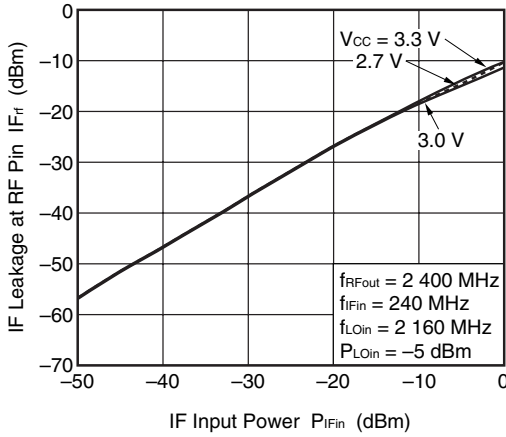
LOCAL LEAKAGE AT IF PIN
vs. LOCAL INPUT LEVEL



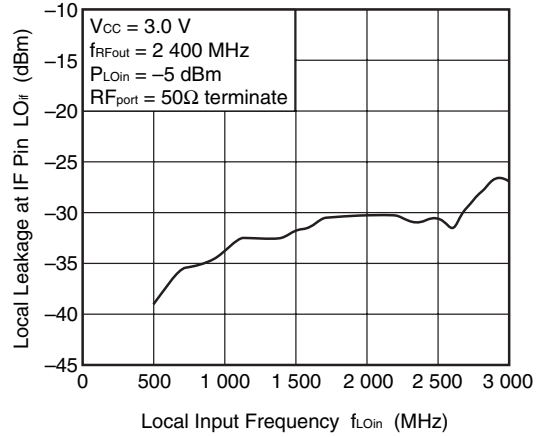
LOCAL LEAKAGE AT RF PIN
vs. LOCAL INPUT LEVEL



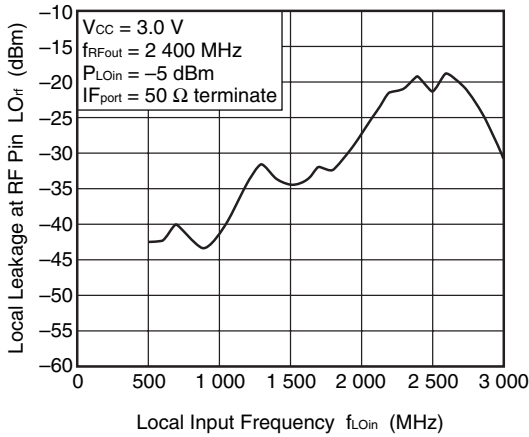
IF LEAKAGE AT RF PIN
vs. IF INPUT POWER



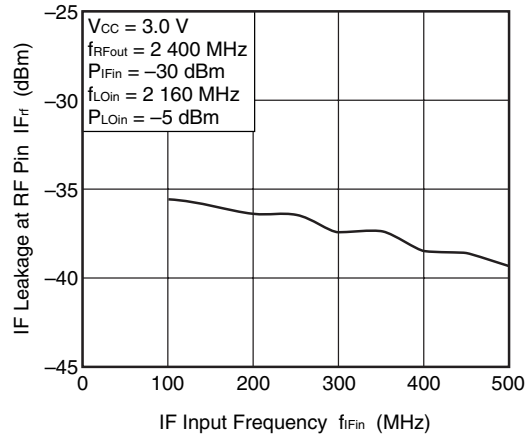
LOCAL LEAKAGE AT IF PIN
vs. LOCAL INPUT FREQUENCY



LOCAL LEAKAGE AT RF PIN
vs. LOCAL INPUT FREQUENCY

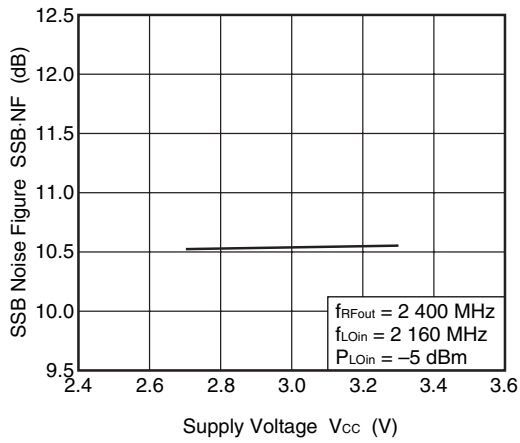


IF LEAKAGE AT RF PIN
vs. IF INPUT FREQUENCY

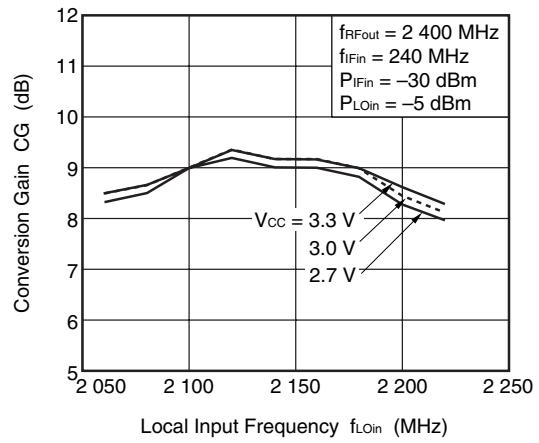


Remark The graphs indicate nominal characteristics.

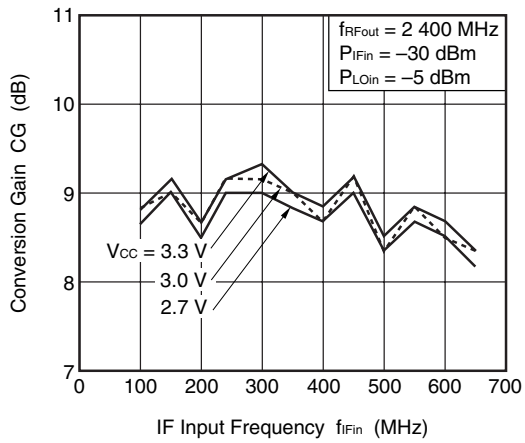
SSB NOISE FIGURE vs. SUPPLY VOLTAGE



CONVERSION GAIN vs. LOCAL INPUT FREQUENCY



CONVERSION GAIN vs. IF INPUT FREQUENCY



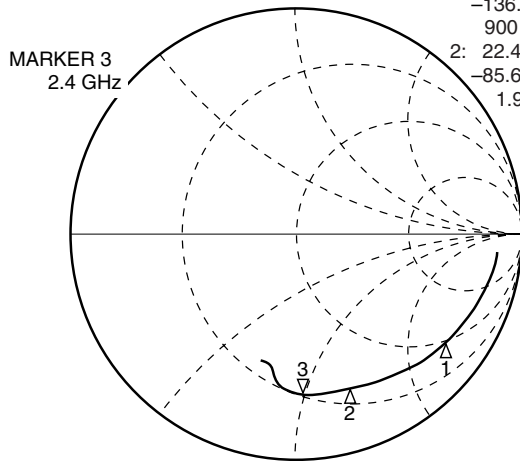
Remark The graphs indicate nominal characteristics.

★ 12. S-PARAMETERS

LO port Impedance (at L loaded)

CH1 B₁₁ 1 U FB B : 17.816 Ω -49.146 Ω 1.3493 pF
2 400.000 000 MHz

1: 45.734 Ω
-136.26 Ω
900 MHz
2: 22.445 Ω
-85.655 Ω
1.90 Hz

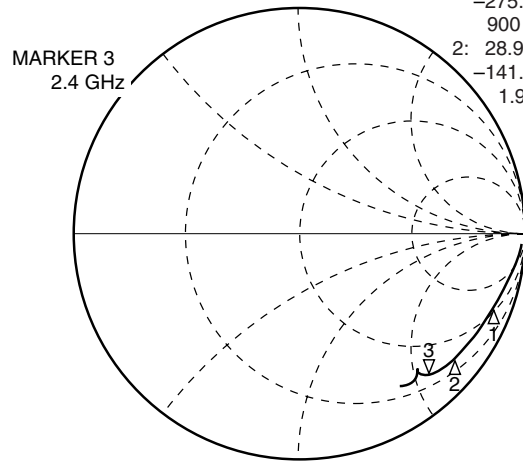


START 100.000 000 MHz
STOP 3 100.000 000 MHz

RF port Impedance (at L loaded)

CH1 B₂₂ 1 U FB B : 22.96 Ω -107.45 Ω 617.19 fF
2 400.000 000 MHz

1: 63.672 Ω
-275.47 Ω
900 MHz
2: 28.953 Ω
-141.21 Ω
1.90 Hz

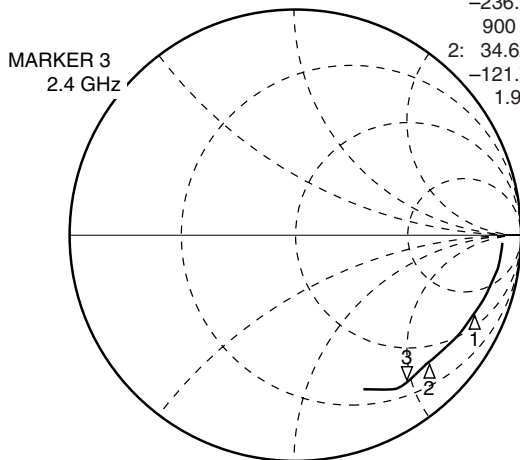


START 100.000 000 MHz
STOP 3 100.000 000 MHz

IF port Impedance (at L loaded)

CH1 B₁₁ 1 U FB B : 25.383 Ω -96.613 Ω 672.47 fF
2 400.000 000 MHz

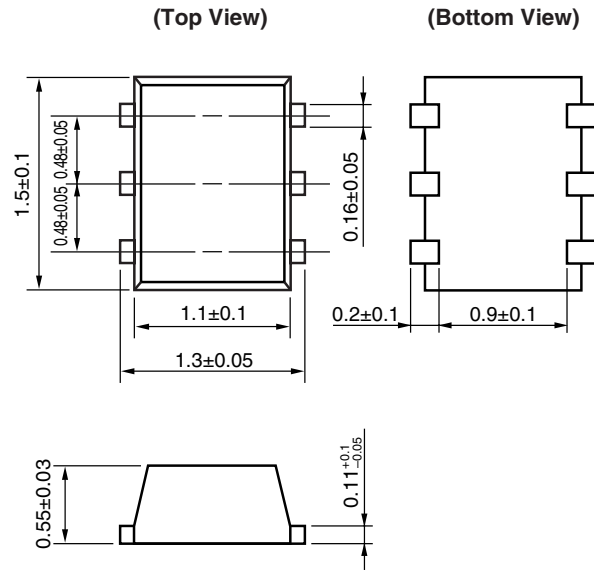
1: 66.539 Ω
-236.11 Ω
900 MHz
2: 34.626 Ω
-121.79 Ω
1.90 Hz



START 100.000 000 MHz
STOP 3 100.000 000 MHz

★ 13. PACKAGE DIMENSIONS

6-PIN LEAD-LESS MINIMOLD (1511) (UNIT: mm)



Remark () : Reference value

14. NOTES ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent undesired oscillation).
- (3) Connect a bypass capacitor (example : 1 000 pF) to the V_{CC} pin.
- (4) Connect a matching circuit to the RF output pin.
- (5) The DC cut capacitor must be attached to input and output pin.

15. RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

| Soldering Method | Soldering Conditions | Condition Symbol |
|------------------|---|------------------|
| Infrared Reflow | Peak temperature (package surface temperature) : 260°C or below Time at peak temperature : 10 seconds or less Time at temperature of 220°C or higher : 60 seconds or less Preheating time at 120 to 180°C : 120±30 seconds Maximum number of reflow processes : 3 times Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below | IR260 |
| Wave Soldering | Peak temperature (molten solder temperature) : 260°C or below Time at peak temperature : 10 seconds or less Preheating temperature (package surface temperature) : 120°C or below Maximum number of flow processes : 1 time Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below | WS260 |
| Partial Heating | Peak temperature (terminal temperature) : 350°C or below Soldering time (per side of device) : 3 seconds or less Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below | HS350 |

Caution Do not use different soldering methods together (except for partial heating).

When the product(s) listed in this document is subject to any applicable import or export control laws and regulation of the authority having competent jurisdiction, such product(s) shall not be imported or exported without obtaining the import or export license.

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M8E 00.4-0110

► For further information, please contact

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